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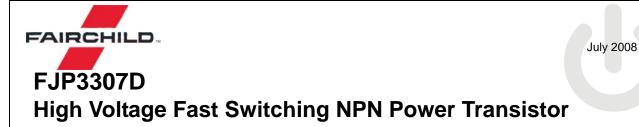


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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Features

- Built-in Diode between Collector and Emitter
- Suitable for Electronic Ballast and Switch Mode Power Supplies



Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	700	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	9	V
I _C	Collector Current (DC)	8	A
I _{CP}	* Collector Current (Pulse)	16	A
Ι _Β	Base Current (DC)	4	A
P _C	Collector Dissipation ($T_C = 25^{\circ}C$)	80	W
Т _Ј	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

* Pulse Test: PW = 300ms, Duty Cycle = 2% Pulsed

Electrical Characteristics $T_{c} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = 500 \mu A, I_{E} = 0$	700			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA, I _B = 0	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 500 \mu A, I_{C} = 0$	9			V
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	mA
h _{FE1} h _{FE2}	DC Current Gain	$V_{CE} = 5V$, $I_C = 2A$ $V_{CE} = 5V$, $I_C = 5A$	8 5		40 30	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 2A, I_{\rm B} = 0.4A$			1	V
		I _C = 5A, I _B = 1A			2	V
		I _C = 8A, I _B = 2A			3	V

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 2A, I_{\rm B} = 0.4A$			1.2	V
		I _C = 5A, I _B = 1A			1.6	V
V _F	Diode Forward Voltage	I _C = 3A			2.5	V
C _{ob}	Output Capatitance	V _{CB} = 10V, I _E = 0, f = 1MHz		60		pF
t _{STG}	Storage Time	$V_{CC} = 125V, I_C = 5A$ $I_{B1} = -I_{B2} = 1A, R_L = 50\Omega$			3	μS
t _F	Fall Time				0.7	μS
t _{STG}	Storage Time	$V_{CC} = 30V, I_C = 5A, L=200\mu H$ I _{B1} =1A, R _{BB} = 0Ω, V _{BE(OFF)} = -5V V _{CLAMP} = 250V			2.3	μS
t _F	Fall Time				150	ns

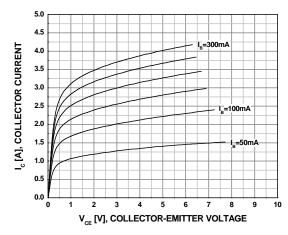
* Pulse test: PW = 300 $\mu s,$ Duty cycl e= 2%

h_{FE} Classification

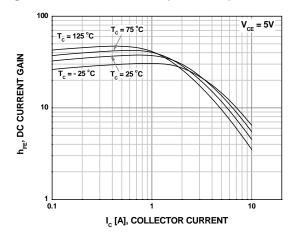
Classification	H1	H2
h _{FE1}	15 ~ 28	26 ~ 39

Typical Characteristics

Figure 1. Static Characterstic









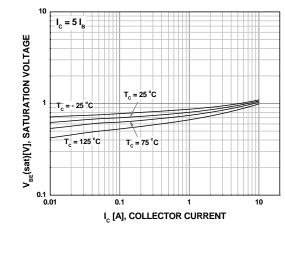


Figure 2. DC Current Gain (H1 Grade)

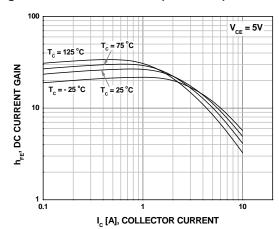
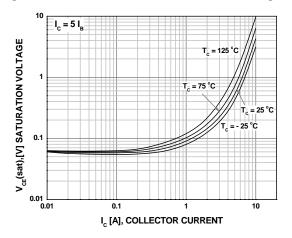
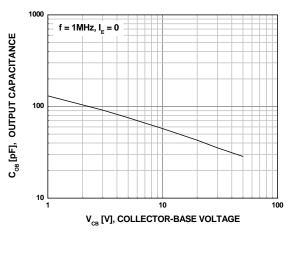


Figure 4. Collector-Emitter Saturation Voltage







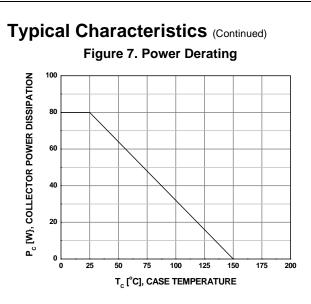


Figure 8. Reverse Biased Safe Operating Area

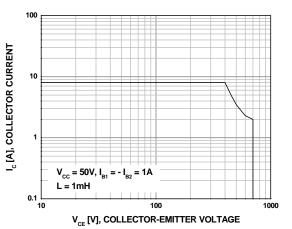
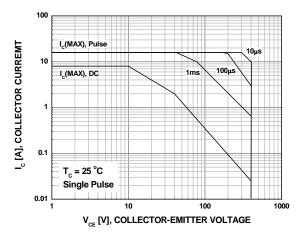


Figure 9. Forward Biased Safe Operating Area





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